

# DATA SHEET

**BYV40E series**  
Rectifier diodes  
ultrafast, rugged

Product specification

September 1998



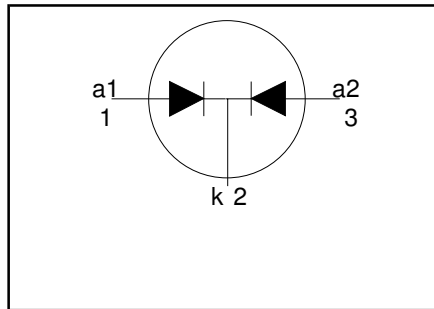
# Rectifier diodes ultrafast, rugged

## BYV40E series

### FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- low profile surface mounting package

### SYMBOL



### QUICK REFERENCE DATA

$V_R = 150\text{ V} / 200\text{ V}$
$V_F \leq 0.7\text{ V}$
$I_{O(AV)} = 1.5\text{ A}$
$I_{RRM} = 0.1\text{ A}$
$t_{tr} \leq 25\text{ ns}$

### GENERAL DESCRIPTION

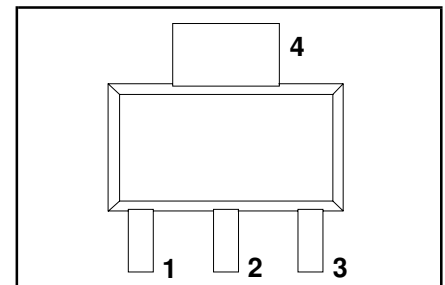
Dual, common cathode, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV40E series is supplied in the SOT223 surface mounting package.

### PINNING

PIN	DESCRIPTION
1	anode 1
2	cathode
3	anode 2
tab	cathode

### SOT223



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
				BYV40E		
$V_{RRM}$	Peak repetitive reverse voltage	$T_{sp} \leq 120^\circ\text{C}$	-	-150	-200	V
$V_{RWM}$	Crest working reverse voltage		-	150	200	V
$V_R$	Continuous reverse voltage		-	150	200	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting) <sup>1</sup>	square wave; $\delta = 0.5$ ; $T_{sp} \leq 132^\circ\text{C}$	-	1.5		A
$I_{FRM}$	Repetitive peak forward current per diode	$t = 25\ \mu\text{s}$ ; $\delta = 0.5$ ; $T_{sp} \leq 132^\circ\text{C}$	-	1.5		A
$I_{FSM}$	Non-repetitive peak forward current per diode	$t_p = 10\text{ ms}$	-	6		A
		$t_p = 8.3\text{ ms}$ sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge; with reapplied $V_{RWM(max)}$	-	6.6		A
$I_{RRM}$	Repetitive peak reverse current per diode	$t_p = 2\ \mu\text{s}$ ; $\delta = 0.001$	-	0.1		A
$I_{RSM}$	Non-repetitive peak reverse current per diode	$t_p = 100\ \mu\text{s}$	-	0.1		A
$T_{stg}$	Storage temperature		-65	150		$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150		$^\circ\text{C}$

<sup>1</sup> Neglecting switching and reverse current losses

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### ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_C$	Electrostatic discharge capacitor voltage	Human body model; $C = 250 \text{ pF}$ ; $R = 1.5 \text{ k}\Omega$	-	8	kV

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-sp}$	Thermal resistance junction to solder point	one or both diodes conducting	-	-	15	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	pcb mounted; minimum footprint pcb mounted; pad area as in fig:11	-	156 70	-	K/W K/W

### ELECTRICAL CHARACTERISTICS

characteristics are per diode at  $T_j = 25 \text{ }^\circ\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 0.5 \text{ A}$ ; $T_j = 150 \text{ }^\circ\text{C}$	-	0.50	0.7	V
		$I_F = 1.5 \text{ A}$	-	0.82	1.0	V
$I_R$	Reverse current	$V_R = V_{RWM}$ ; $T_j = 100 \text{ }^\circ\text{C}$	-	100	300	$\mu\text{A}$
		$V_R = V_{RWM}$	-	5	10	$\mu\text{A}$
$Q_s$	Reverse recovery charge	$I_F = 2 \text{ A}$ ; $V_R \geq 30 \text{ V}$ ; $-di_F/dt = 20 \text{ A}/\mu\text{s}$	-	-	11	nC
$t_{rr1}$	Reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R \geq 30 \text{ V}$ ; $-di_F/dt = 100 \text{ A}/\mu\text{s}$	-	-	25	ns
$t_{rr2}$	Reverse recovery time	$I_F = 0.5 \text{ A}$ to $I_R = 1 \text{ A}$ ; $I_{rec} = 0.25 \text{ A}$	-	10	20	ns
$V_{fr}$	Forward recovery voltage	$I_F = 2 \text{ A}$ ; $di_F/dt = 20 \text{ A}/\mu\text{s}$	-	3	-	V

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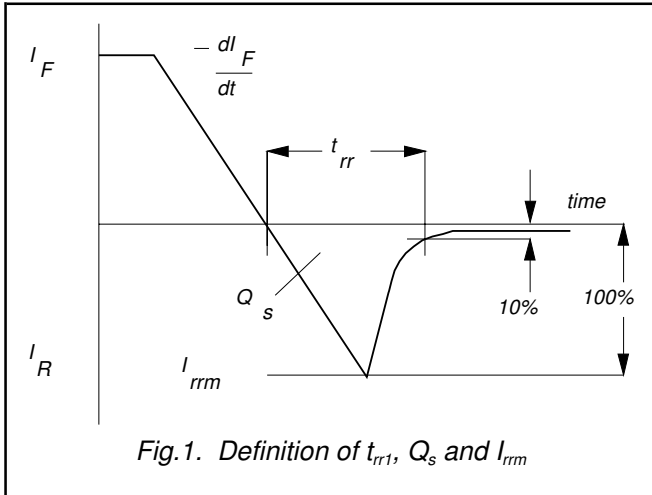


Fig.1. Definition of  $t_{rr1}$ ,  $Q_s$  and  $I_{rm}$

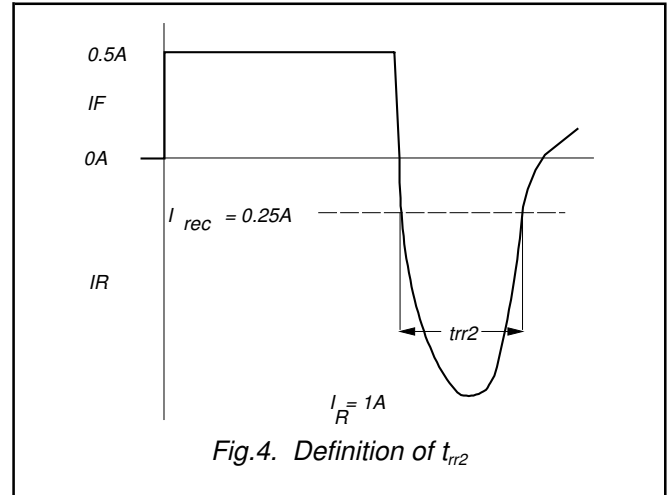


Fig.4. Definition of  $t_{rr2}$

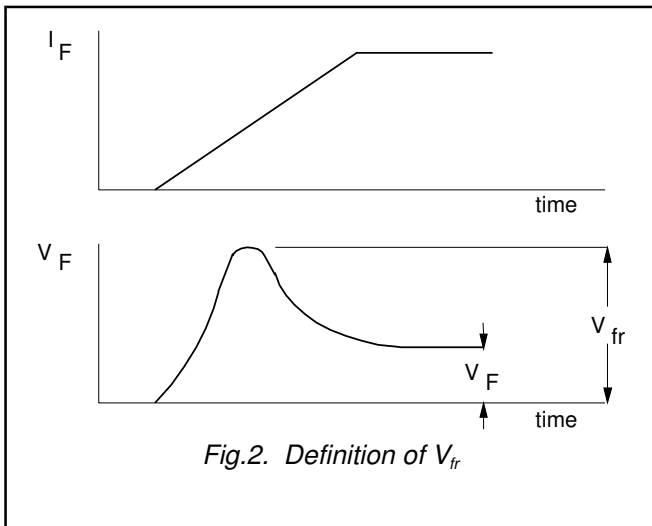


Fig.2. Definition of  $V_{fr}$

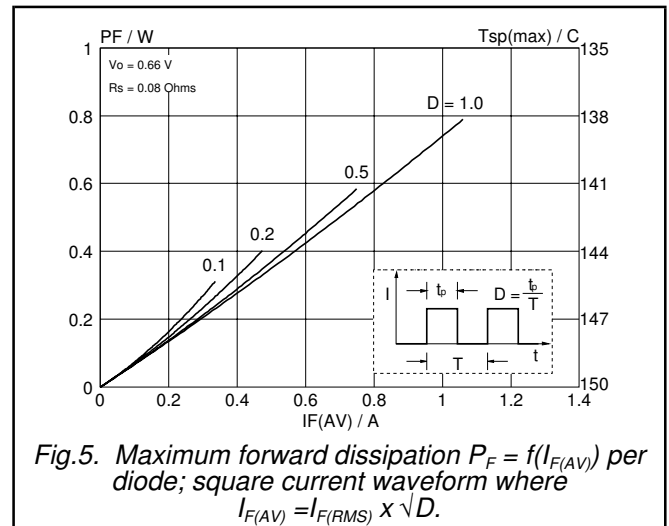


Fig.5. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; square current waveform where  $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

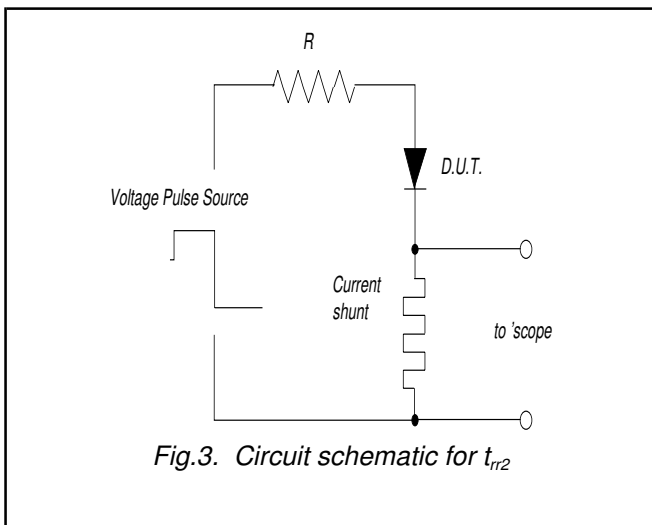


Fig.3. Circuit schematic for  $t_{rr2}$

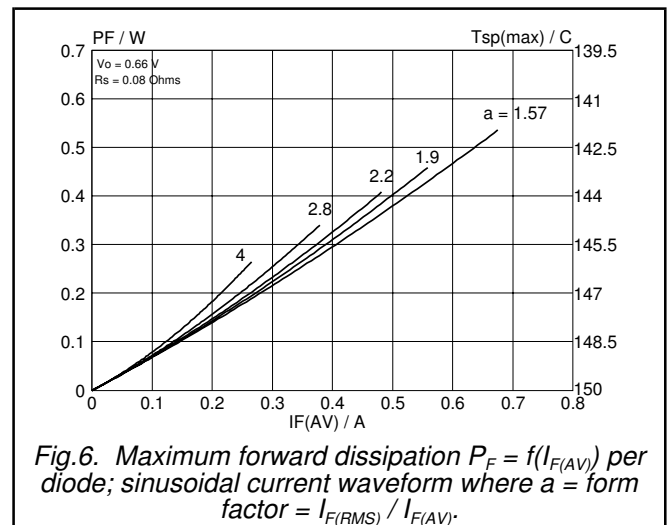


Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; sinusoidal current waveform where  $a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$ .

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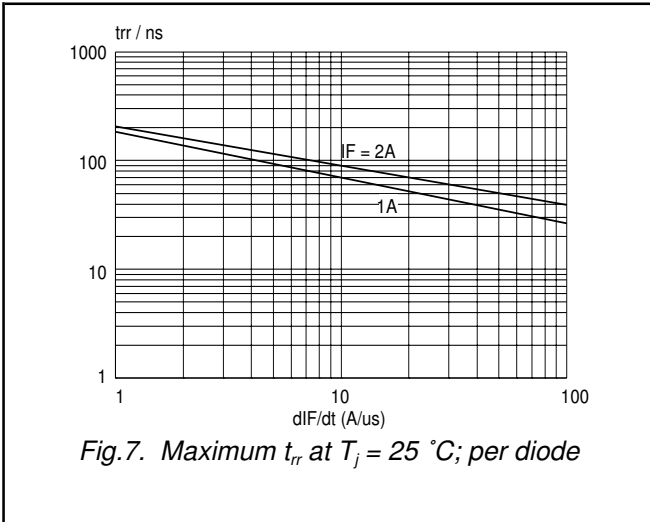


Fig.7. Maximum  $t_{rr}$  at  $T_j = 25\text{ }^\circ\text{C}$ ; per diode

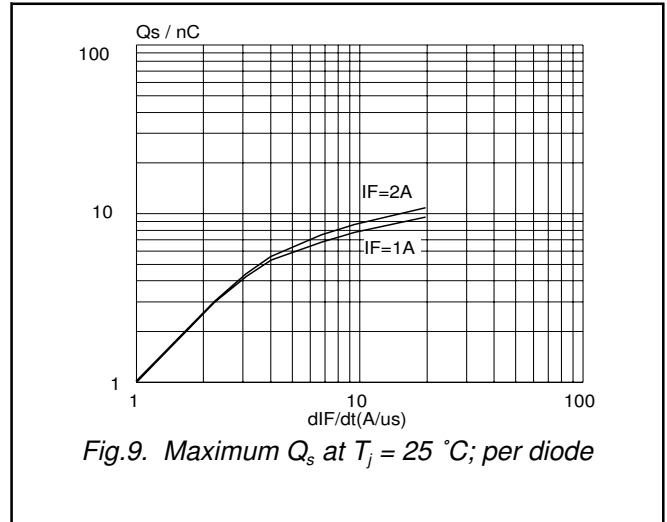


Fig.9. Maximum  $Q_s$  at  $T_j = 25\text{ }^\circ\text{C}$ ; per diode

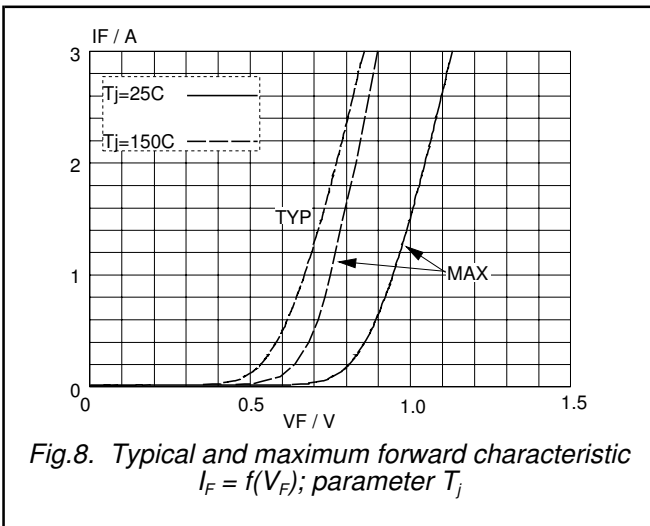


Fig.8. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$

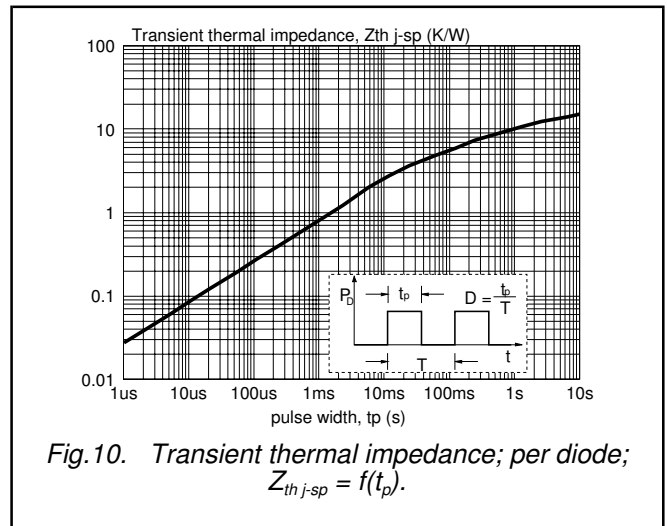
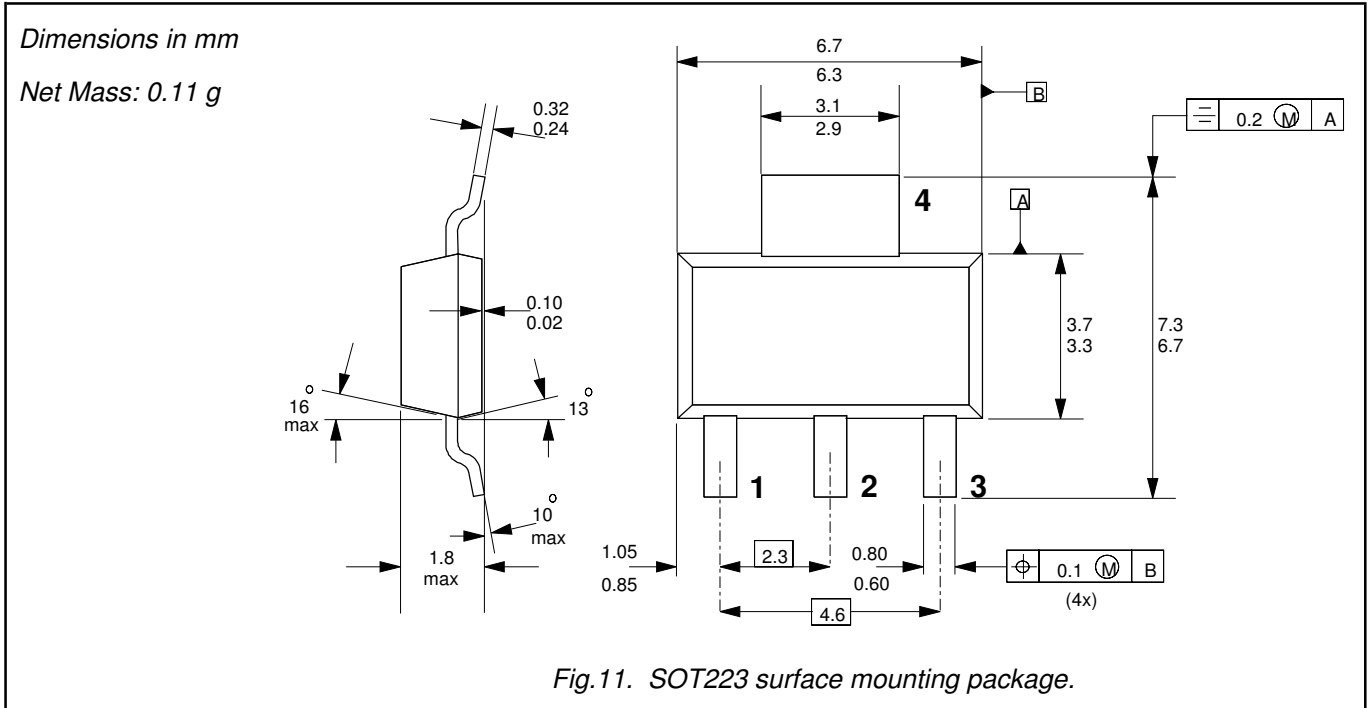


Fig.10. Transient thermal impedance; per diode;  $Z_{th\ j-sp} = f(t_p)$ .

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**MECHANICAL DATA**



**Notes**

1. For further information, refer to Philips publication SC18 "SMD Footprint Design and Soldering Guidelines".  
Order code: 9397 750 00505.
2. Epoxy meets UL94 V0 at 1/8".

## Legal information

### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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